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Wednesday, August 26

Session: WE1A

Special Session (Invited)

Wireless Medical Sensors and Low-Noise Technologies

Room A 15:00-16:30

Wednesday, August 26

Chair: Toshihiko Hamasaki, Hiroshima Institute of Technology

- | | | |
|-------------------------------|---|---|
| <u>WE1A-1</u> | An Ultra-Low-Power Wireless Transceiver SoC for Medical Applications
S. Masui ¹ , K. Kanda ¹ , K. Oishi ¹ , K. Philips ² , H. de Groot ² , ¹ Fujitsu Laboratories, Kawasaki, Japan,
² Holst Centre, Eindhoven, Netherlands | 1 |
| <u>WE1A-2</u> | Development of Low-Power Analog/RF Mixed-Signal Circuits with Flexible Thin Film Devices for
Wireless BMI Systems
I. Akita, Toyohashi University of Technology, Toyohashi, Japan | 4 |
| <u>WE1A-3</u> | On-Chip and On-Board RF Noise Coupling and Impacts on LTE Wireless Communication Performance
M. Nagata ¹ , N. Miura ¹ , S. Muroga ² , S. Tanaka ³ , M. Yamaguchi ³ , ¹ Kobe University, Kobe, Japan, ² Natl. Inst.
of Tech. Toyota College, Toyota, Japan, ³ Tohoku University, Sendai, United States | 7 |

Session: WE2A

Special Session (Invited)

Low-Power CMOS Transceivers

Room A 16:50-18:20

Wednesday, August 26

Chair: Minoru Fujishima, Hiroshima University

- | | | |
|-------------------------------|--|----|
| <u>WE2A-1</u> | Low-power SoC design techniques for Bluetooth / Bluetooth Low Energy
H. Majima, Toshiba Corporation, Kawasaki, Japan | 10 |
| <u>WE2A-2</u> | "Easy-to-use" RF-solutions for IoT applications
Y. Hayashi, K. Yahagi, H. Sato, K. Sato, M. Muratani, Renesas Electronics Corporation, Kodaïra, Japan | 13 |
| <u>WE2A-3</u> | An Ultra-Low-Power 32QAM RF Transmitter
H. Ito, A. Shirane, N. Ishihara, K. Masu, Tokyo Institute of Technology, Yokohama, Japan | 16 |

Thursday, August 27

Session: TH1A

Millimeter-wave Circuits and Systems

Room A 08:20-10:20

Thursday, August 27

Chair: Kazuaki Takahashi, Panasonic

- | | | |
|-------------------------------|---|----|
| <u>TH1A-1</u> | Smart RFIC: Millimeter-wave Gigabit Transceivers with Digitally-enabled Built-in Self-calibration and Auto-switching Functions: From Single-ended ILFD Toward Differential Miller Frequency Divider (Invited)
T. Huang, National Taiwan University, Taipei, Taiwan | 19 |
| <u>TH1A-2</u> | A 60GHz CMOS Transceiver Considering HCI Reliability (Invited)
K. Okada, Tokyo Institute of Technology, Tokyo, Japan | 22 |
| <u>TH1A-3</u> | A Broadband Doubler with Harmonic Rejection in 90nm CMOS
B. Chen, Y. Hsiao, H. Wang, National Taiwan University, Taipei, Taiwan | 25 |
| <u>TH1A-4</u> | An Optimum Inductive Matched Cascode LNA in 60GHz-Band
H. Mizutani ¹ , E. Taniguchi ¹ , M. Tsuru ¹ , R. Inagaki ¹ , S. Kameda ² , N. Suematsu ² , T. Takagi ² , K. Tsubouchi ² ,
¹ Mitsubishi Electric Corporation, Kamakura, Japan, ² Tohoku University, Sendai, Japan | 28 |
| <u>TH1A-5</u> | A 60GHz 360° Digitally Controlled Phase Shifter with 6-bit Resolution and 2.3° Maximal rms Phase Error in 65nm CMOS Technology
D. Huang, L. Zhang, D. Li, L. Zhang, Y. Wang, Tsinghua University, Beijing, China | 31 |

Session: TH1B

Advanced Integration and Packaging Technology

Room B 08:20-10:20

Thursday, August 27

Chair: Noriharu Suematsu, Tohoku University

- | | | |
|-------------------------------|--|----|
| <u>TH1B-1</u> | A Low-Cost DC-to-92 GHz Broadband Three-Path Bondwire Interconnect
W. Wu ¹ , M. Yu ¹ , C. Li ¹ , C. Kuo ² , ¹ National Central University, Zhongli City, Taiwan,
² National Chiao Tung University, Hsinchu City, Taiwan | 34 |
| <u>TH1B-2</u> | Quad-band Receiver Front-end Module using SiGe BiCMOS MMICs and LTCC Triplexer
T. Kaho ¹ , S. Oshima ² , Y. Yamaguchi ¹ , T. Nakagawa ¹ , ¹ NTT Corporation, Yokosuka, Japan,
² Oyama National College of Technology, Oyama, Japan | 37 |

<u>TH1B-3</u>	An Integrated Configuration of Antennas and Filters for Front-End Module in Massive-MIMO Transmitter Y. Suzuki, K. Satoh, M. Sumi, A. Fukuda, S. Narahashi, Ntt docomo, Yokosuka, Japan	40
<u>TH1B-4</u>	Robust Design of CMOS Wireless SoC for 3D-Integrated Small TransferJet(TM) Module (Invited) K. Agawa, I. Seto, D. Miyashita, M. Okano, Toshiba Corporation, Kawasaki, Japan	43
<u>TH1B-5</u>	3D Integration Using Inductive Coupling and Coupled Resonator (Invited) Y. Take, J. Kadomoto, T. Kuroda, Keio University, Yokohama, Japan	46

Session: TH2A

Toward THz area

Room A 10:40-12:20

Thursday, August 27

Chair: Toshihide Suzuki, Fujitsu Lab

<u>TH2A-1</u>	Millimeter Wave CMOS Integrated Circuit for Multi-Gigabit Communication and Radar Applications (Invited) J. Sato, K. Takinami, K. Takahashi, Panasonic Corporation, Yokohama, Japan	49
<u>TH2A-2</u>	Demonstration of KIOSK Data Downloading System at 300 GHz Based on InP MMICs (Invited) H. Song, T. Tajima, T. Kosugi, H. Hamada, A. E. Moutaouakil, H. Sugiyama, H. Matsuzaki, M. Yaita, S. Kodama, O. Kagami, Nippon Telegraph and Telephone Corporation, Atsugi, Japan	52
<u>TH2A-3</u>	Compact 138-GHz Amplifier with 18-dB Peak Gain and 27-GHz 3-dB Bandwidth S. Hara ¹ , K. Katayama ² , K. Takano ² , I. Watanabe ¹ , N. Sekine ¹ , A. Kasamatsu ¹ , T. Yoshida ² , S. Amakawa ² , M. Fujishima ² , ¹ National Institute of Information and Communications Technology, Koganei, Japan, ² Hiroshima University, Higashihiroshima, Japan	55
<u>TH2A-4</u>	A CMOS Triple-Push 280-GHz VCO Integrated with 1/16,384 Divider Chain J. Yoo, N. Kim, J. Yun, M. Seo, J. Rieh, Korea University, Seoul, Republic of Korea	58

Session: TH2B

Metamaterials Circuits and Devices

Room B 10:40-12:10

Thursday, August 27

Chair: Atsushi Sanada, Yamaguchi University

<u>TH2B-1</u>	Wavelength selective filters using metamaterials in terahertz frequency region (Invited) Y. Kanamori, Tohoku university, Sendai, Japan	61
<u>TH2B-2</u>	Tunability of Dual-frequency Immittance Inverters on Dual-composite Right/Left-handed Transmission Lines (D-CRLH TL) with Variable Capacitors D. Kholodnyak, E. Zameshaeva, V. Turgaliev, E. Vorobev, St. Petersburg Electrotechnical University "LETI", St. Petersburg, Russian Federation	64

TH2B-3	CMOS Sub-THz On-chip Modulator by Stacked Split Ring Resonator with High-extinction Ratio Y. Liang ¹ , H. Yu ¹ , W. Zhang ² , F. Lin ² , ¹ Nanyang Technological University, Singapore, Singapore, ² University of Science and Technology of China, Hefei, China	67
TH2B-4	Printed Spiral Metamaterial Resonators for Wireless Powering System with Proximal Metal Plates C. Liou ¹ , C. Kuo ² , S. Lin ¹ , S. Mao ¹ , ¹ National Taiwan University, Taipei, Taiwan, ² National Taipei University of Technology, Taipei, Taiwan	70

Session: TH3A
Amplifier Design Techniques
Room A 13:20-15:20
Thursday, August 27

Chair:	Kenjiro Nishikawa, Kagoshima University	
TH3A-1	A Review of recent development on digital transmitter with integrated GaN switching amplifiers (Invited) R. Ma, Mitsubishi Electric Research Laboratories, Cambridge, United States	73
TH3A-2	Cryogenic Low Noise Amplifier for Phased Array Antenna (Invited) H. Kayano, TOSHIBA Corporation, Kawasaki, Japan	76
TH3A-3	A High Gain Broadband LNA in GaAs 0.15- μ m pHEMT Process Using Inductive Feedback Gain Compensation for Radio Astronomy Applications Y. Wang ¹ , C. Chiong ² , J. Nai ¹ , H. Wang ¹ , ¹ National Taiwan University, Taipei, Taiwan, ² Academia Sinica, Taipei, Taiwan	79
TH3A-4	A Low-power High-Q Matching LNA with Small-Size Matching Calibration Circuit for Low Power Receiver T. Ta, H. Okuni, A. Sai, M. Furuta, Toshiba Corp., Kawasaki, Japan	82
TH3A-5	A 1-4GHz CMOS Receive Front-End for Digital Array Radars Z. Duan ^{1,2} , X. Tang ² , Q. Ma ² , Y. Dai ² , F. Lin ¹ , ¹ University of Science and Technology of China, Hefei, China, ² East China Research Institute of Electronic Engineering, Hefei, China	85

Session: TH3B
Measurement Technologies
Room B 13:20-14:40
Thursday, August 27

Chair:	Masayuki Kimishima, Advantest Laboratory	
TH3B-2	Broadband Measurement System for the Specific Absorption Rate above 300 MHz R. Shimofusa, Y. Okano, Tokyo City University, Tokyo, Japan	88
TH3B-3	Comparative Analysis of On-Chip Transmission Line De-Embedding Techniques S. Amakawa, K. Katayama, K. Takano, T. Yoshida, M. Fujishima, Hiroshima University, Higashihiroshima, Japan	91
TH3B-4	Calibration of Process Parameters for Electromagnetic Field Analysis of CMOS Devices up to 330 GHz K. Takano ¹ , K. Katayama ¹ , S. Hara ² , A. Kasamatsu ² , T. Yoshida ¹ , S. Amakawa ¹ , M. Fujishima ¹ ,	94

TH3B-5	¹ Hiroshima University, Higashi-Hiroshima, Japan, ² National Institute of Information and Communications Technology, Koganei, Japan Characterization of Cross-Line up to 110 GHz Using Two-Port Measurements K. K. Tokgoz, S. Maki, K. Okada, A. Matsuzawa, Tokyo Institute of Technology, Meguro-ku, Japan	97
------------------------	---	----

Session: TH4A
Control Circuit Design and Analysis
Room A 16:20-17:50
Thursday, August 27

Chair:	Tsuneo Tokumitsu, Sumitomo Electric	
TH4A-1	Complex Signal Processing Used in Modern RF Transceivers (Invited) T. Tsukahara, R. Ito, K. Arimura, University of Aizu, Aizu-Wakamatsu, Japan	100
TH4A-2	Parasitic Conscious 54 GHz Divide-by-4 Injection-Locked Frequency Divider K. Katayama, S. Amakawa, K. Takano, M. Fujishima, Hiroshima University, Higashi-Hiroshima, Japan	103
TH4A-3	Highly Linear High Isolation SPDT Switch IC with Back-gate Effect and Floating Body Technique in 180-nm CMOS X. Xu, X. Yang, Z. Sun, T. A. Kurniawan, T. Yoshimasu, Waseda University, Kitakyushu, Japan	106
TH4A-4	Analysis on the Linearity of the Balanced Diode Mixer Driven by the Square Wave LO H. Hama, K. Itoh, K. Noguchi, T. Hirota, S. Makino, Kanazawa Institute of Technology, Ohgigaoka, Japan	109

Session: TH4B
Special Session (Invited)
Advances in Analog and Mixed Signal Ics
Room A 16:20-17:20
Thursday, August 27

Chair:	Hiroki Ishikuro, Keio University	
TH4B-2	DC–DC conversion techniques for low-voltage power supplies T. Ueno ¹ , T. Ogawa ¹ , T. Miyazaki ² , T. Itakura ¹ , ¹ Toshiba Corporation, Kawasaki, Japan, ² Toshiba Corporation, Kawasaki, Japan	112
TH4B-3	Sophisticated circuit design and simulation method for switching power converters Y. Sugimoto, Chuo University, Tokyo, Japan	115

Session: THIFA
RFIT2015 Interactive Forum
Room IF 15:20-16:20
Thursday, August 27

Chair: Hiroshi Okazaki, NTT DOCOMO, INC.

<u>THIFA-1</u>	RFIC Flip-Chip Interconnection Using a Fiber Type Anisotropic Conductive Film. T. Owada, M. Motoyoshi, S. Kameda, N. Suematsu, T. Takagi, K. Tsubouchi, Tohoku University, Sendai, Japan	118
<u>THIFA-2</u>	Wideband CMOS Mixer Using Differential Circuit Transconductance Linearization Technique L. Liu, K. Zhang, Z. Ren, X. Zou, Z. Lu, D. Liu, Huazhong University of Science and Technology, Wuhan, China	121
<u>THIFA-3</u>	Power-Amplifier Inserted Transversal Filter using High-Order Pass Band K. Nagasawa, S. Fujioka, K. Watanabe, Y. Umeda, Y. Kozawa, Tokyo University of Science, 2641 Yamazaki, Japan	124
<u>THIFA-4</u>	Trial Fabrication of PTFE-Based E-Plane Waveguide Coupler for Short Millimeter-Wave by SR Etching M. Kishihara ¹ , M. Murakami ² , A. Yamaguchi ² , Y. Utsumi ² , I. Ohta ³ , ¹ Okayama Prefectural University, Soja, Japan, ² University of Hyogo, Kamigori, Ako, Japan, ³ University of Hyogo, Kobe, Japan	127
<u>THIFA-5</u>	Design of 60-GHz Amplifiers Based on Over Neutralization and Optimized Inter-Stage Matching Networks in 65-nm CMOS D. Li, L. Zhang, Y. Wang, Tsinghua University, Beijing, China	130
<u>THIFA-6</u>	A Low Noise Amplifier With Coupled Matching Structure For V-Band Applications Y. Chiang, Y. Lin, National Chung Hsing University, Taichung, Taiwan	133
<u>THIFA-7</u>	A 60 GHz Single-Chip CMOS Transceiver for High-Definition Video Transmission System Application C. H. Hsieh, D. W. Pan, Z. M. Tsai, National Chung Cheng University, Chiayi, Taiwan	136

Friday, August 28

Session: FR1A

Analog and Mixed Signal ICs for System Applications

Room A 08:20-10:20

Friday, August 28

Chair: Kenichi Ohhata, Kagoshima University

FR1A-1	Wireless Sensor Microsystems for Emerging Biomedical Applications (Invited) M. Je, DGIST, Daegu, Republic of Korea	139
FR1A-2	20 MHz Carrier Frequency AM Receiver in Flexible a-IGZO TFT Technology with Textile Antennas (Invited) K. Ishida ¹ , R. Shabanpour ¹ , T. Meister ¹ , B. Kheradmand Boroujeni ¹ , C. Carta ¹ , F. Ellinger ¹ , L. Petti ² , N. Münzeinrieder ² , G. A. Salvatore ² , G. Tröster ² , ¹ Technische Universität Dresden, Dresden, Germany, ² Swiss Federal Institute of Technology, Zurich, Switzerland	142
FR1A-3	Self-directed Beamforming IF receiver for Broadband Communication Using Low Frequency Loop Control M. Motoyoshi, M. Nakamura, S. Kameda, N. Suematsu, T. Takagi, K. Tsubouchi, Tohoku University, Sendai, Japan	145
FR1A-4	A 0.8-1.9GHz-Band CMOS Direct Digital RF Quadrature Modulator N. Suematsu, O. Wada, S. Kameda, T. Takagi, K. Tsubouchi, Tohoku University, Sendai, Japan	148
FR1A-5	Modeling of wideband decoupling power line for millimeter-wave CMOS circuits R. Goda, S. Amakawa, K. Katayaka, K. Takano, T. Yoshida, M. Fujishima, Hiroshima University, Higashihiroshima, Japan	151

Session: FR1B

Power Amplifiers

Room B 08:20-10:20

Friday, August 28

Chair: Koji Yamanaka, Mitsubishi Electric

Co-Chair: Shintaro Shinjo, Mitsubishi Electric

FR1B-1	Linearization of RF CMOS Power Amplifiers (Invited) G. Jeong ¹ , B. Koo ² , T. Joo ³ , S. Hong ¹ , ¹ KAIST, Daejeon, Republic of Korea, ² Qualcomm, San Diego, United States, ³ Samsung Electronics, Suwon, Republic of Korea	154
------------------------	--	-----

FR1B-2	GHz-band CMOS Class-E Power Amplifier Module Considering Wire Bonding (Invited) H. Kanaya, Kyushu University, Fukuoka, Japan	157
FR1B-3	A Power Amplifier with Envelope Tracking used for Cellular Front-End Module based on 0.18 μ m SOI CMOS Process Y. Xiao, C. Yao, Z. Li, Y. Liu, H. Zhang, Institute of Microelectronics, Chinese Academy of Sciences, Beijing, China	160
FR1B-4	A High Efficiency, 3-7 GHz, Class AB CMOS Power Amplifier for WBAN Applications A. Gadallah ¹ , A. Allam ¹ , H. Mosalam ¹ , A. Abdelrahman ¹ , J. Hongting ² , R. Pokharel ² , ¹ Egypt Japan University of Science and Technology , Alexandria , Egypt, ² Kyushu University , Fukuoka, Japan	163
FR1B-5	A 76-81 GHz High Efficiency Power Amplifier for Phased Array Automotive Radar Applications I. Soga, Y. Yagishita, H. Matsumura, Y. Kawano, T. Suzuki, T. Iwai, Fujitsu laboratories, Atsugi, Japan	166

Session: FR2A

Data Converters

Room A 10:40-12:20

Friday, August 28

Chair: Yohtaro Umeda, Tokyo University of Science

FR2A-1	Trends in the Design of High-speed, Low-power Analog-to-Digital Converters (Invited) M. Furuta, T. Itakura, Toshiba Corporation, Kawasaki, Japan	169
FR2A-2	High-Speed, Low-Power Subranging ADCs (Invited) K. Ohhata, Kagoshima University, Kagoshima, Japan	172
FR2A-3	Wave Monitor for Glitch Detection and Skew Adjusting in High-Speed DAC K. Tokonami, K. Kohira, H. Ishikuro, Keio University, Yokohama, Japan	175
FR2A-4	A Gray Code Based Time-to-Digital Converter Architecture and its FPGA Implementation C. Li, H. Kobayashi, Gunma University, Kiryu, Japan	178

Session: FR2B

Millimeter-Wave Dividers and Digitally-Controlled Oscillators

Room B 10:40-12:20

Friday, August 28

Chair: Nobuyuki Itoh, Okayama Prefectural Univ.

Co-Chair: Toshihiko Yoshimasu, Waseda University

FR2B-1	An 80 GHz Programmable Frequency Divider for Wideband mm-Wave Frequency Ramp Synthesis M. van Delden ¹ , G. Hasenaecker ¹ , N. Pohl ² , K. Aufinger ³ , T. Musch ¹ , ¹ Ruhr-Universität Bochum, Bochum, Germany, ² Fraunhofer-Institut für Hochfrequenzphysik und Radartechnik FHR, Wachtberg, Germany, ³ Infineon Technologies AG, Neubiberg, Germany	181
------------------------	---	-----

FR2B-2	Evaluation of A D-band Divide-by-3 Injection-locked Frequency Divider in 65 nm CMOS Process Y. Yeh ¹ , Y. Liu ¹ , H. Chang ¹ , K. Chen ² , ¹ National Central University, Jhongli, Taiwan, ² ITRI, Hsinchu, Taiwan	184
FR2B-3	A Low-Voltage Design of Digitally-Controlled Oscillator Based on the gm/ID Methodology J. Bae ¹ , S. Radhapuram ¹ , I. Jo ¹ , T. Kihara ² , T. Matsuoka ¹ , ¹ Osaka University, Suita-shi, Japan, ² Osaka Institute of Technology, Asahi-ku, Japan	187
FR2B-4	A 0.55V 100MHz ADPLL with Delta-Sigma LDO and Relaxation DCO in 65nm CMOS Y. Zhang ¹ , W. Rhee ¹ , T. Kim ² , H. Park ² , Z. Wang ¹ , ¹ Tsinghua University, Beijing, China, ² Samsung Electronics, Yongin, Republic of Korea	190
FR2B-5	A Digital-Intensive F/PLL-Based Two-Point Modulator with a Constant-Gain DCO for Linear FMCW Generation N. Xu, S. Lv, W. Rhee, Z. Wang, Tsinghua University, Beijing, China	193

Session: FR3A

Wireless Power Transfer I - Antenna and Semi-conductors -
Room A 13:20-15:20
Friday, August 28

Chair: Kenjiro Nishikawa, Kagoshima University

FR3A-1	GaN HEMT high efficiency amplifier for Microwave Wireless Power Transmission (Invited) Y. Yamaguchi ¹ , M. Hangai ¹ , K. Yamanaka ¹ , Y. Homma ² , ¹ Mitsubishi Electric Corporation, Kamakura, Japan, ² Mitsubishi Electric Corporation, Amagasaki, Japan	196
FR3A-2	High breakdown voltage GaAs schottky diode for a high efficiency rectifier in microwave power transmission systems (Invited) T. Tanaka, M. Nakamura, Y. Yamaguchi, M. Tsuru, Y. Aihara, A. Yamamoto, Y. Homma, E. Taniguchi, Mitsubishi Electric Corporation, Amagasaki-city, Japan	199
FR3A-3	A Phased Array Antenna System Employing Frequency-Upconverted Local Signals with Phase Difference A. Fukuda, H. Okazaki, S. Narahashi, NTT DOCOMO, Inc., Yokosuka, Japan	202
FR3A-4	Embedded Antenna Design Based on Zero and Pole Resonances for Wireless Sensor Modules for Applications in Advanced Greenhouses C. Liu, S. Yang, T. Cheng, S. Chen, National Taiwan University, Taipei, Taiwan	205
FR3A-5	Study on Effective pattern of Magnetic Sheet Attached on NFC Antenna T. Sekiguchi ¹ , Y. Okano ¹ , N. Ohmura ² , S. Ogino ² , ¹ Tokyo City University, Tokyo, Japan, ² Microwave Absorbers Inc., Tokyo, Japan	208
FR3A-6	Power Loss Formula for Impedance Matching Circuits Dedicated to Wireless Power Transfer K. Yamada, N. Sakai, T. Ohira, Toyohashi University of Technology, Toyohashi, Japan	211

Session: FR3B
Special Session (Invited)
System and Device Technologies
Room B 13:20-15:20
Friday, August 28

Chair: Minoru Fujishima, Hiroshima University

FR3B-1	Study of Reliable Networking for Short-Range Autonomous Sensor Node T. Hamasaki, Hiroshima Institute of Technology, Hiroshima, Japan	214
FR3B-2	Impact of Anomalous Skin Effect on Metal Wire for Terahertz Integrated Circuit A. Tsuchiya, H. Onodera, Kyoto University, Kyoto, Japan	217
FR3B-3	Nitridation Interfacial-Layer Technology for Enhanced Stability in GaN-Based Power Devices S. Yang, S. Liu, C. Liu, Y. Lu, K. J. Chen, The Hong Kong University of Science and Technology, Hong Kong, China	220
FR3B-4	Large-Signal Modeling of GaN Devices with Emphasis on Trapping Effect and Thermal Challenges F. Lin, W. Qian, L. Li, M. Khan, University of Science and Technology of China (USTC), Hefei, China	223

Session: FR4A
Wireless Power Transfer II - Circuits and Systems -
Room A 15:40-17:10
Friday, August 28

Chair: Naoki Shinohara, Kyoto University

FR4A-1	RF Bridge Rectifier and its good possibility for wireless power transmission systems (Invited) K. Itoh, Kanazawa Institute of Technology, Nonoichi, Japan	226
FR4A-2	Theoretical Analysis on DC-DC Converter for Impedance Matching of a Rectifying Circuit in Wireless Power Transfer Y. Huang, N. Shinohara, T. Mitani, Kyoto University, Uji, Japan	229
FR4A-3	Wireless Sensor Network System with Wireless Powering by Time Division Operation at 5.8 GHz in a Reusable Rocket S. Yoshida ^{1,3} , N. Hasegawa ^{1,2} , Y. Kobayashi ¹ , A. Miyachi ¹ , H. Sakaki ³ , K. Nishikawa ³ , Y. Moriguchi ⁴ , S. Furuta ⁴ , C. Maekawa ⁵ , I. Urushibara ⁵ , S. Kawasaki ¹ , ¹ JAXA, Sagami-hara, Japan, ² Kyoto Univ., Uji, Japan, ³ Kagoshima Univ., Kagoshima, Japan, ⁴ NEC Network and Sensor Systems, Ltd., Fuchu, Japan, ⁵ AR'S Co., Ltd., Yokohama, Japan	232
FR4A-4	Shield Effects of Metal Plate and Mesh in Wireless Power Delivery System J. Hashiba, T. Kawajiri, R. Shibuya, H. Ishikuro, Keio University, Yokohama, Japan	235

Session: FR4B
Device and Circuit Technologies
Room B 15:40-17:10
Friday, August 28

Chair: Hiroshi Okazaki, NTT DOCOMO, INC.

FR4B-1	High-speed III-V devices for millimeter-wave receiver applications (Invited) T. Takahashi ^{1,2} , M. Sato ^{1,2} , K. Makiyama ^{1,2} , Y. Nakasha ^{1,2} , N. Hara ^{1,2} , T. Iwai ¹ , ¹ Fujitsu Laboratories Ltd., Atsugi, Japan, ² Fujitsu Limited, Atsugi, Japan	238
FR4B-2	A K-band Low Noise Amplifier with On-chip Baluns in 90nm CMOS Z. Liu, P. Gao, Z. Chen, Beijing Institute of Technology, Beijing, China	241
FR4B-3	A Dual-Band SiGe HBT Active Load Using Stacked LC Resonators and RC Series Feedback Circuits Y. Itoh, H. Mizuo, A. Ohta, Shonan Institute of Technology, Fujisawa, Japan	244
FR4B-4	A 10 MHz - 6 GHz High Power High Linearity 35 dB Digital Step Attenuator MMIC Using GaN HEMTs with TaON Passivation T. Tsushima ¹ , H. Takeuchi ² , M. Kimishima ¹ , ¹ Advantest Laboratories, Ltd., Sendai, Japan, ² Advantest, Ora-gun, Japan	247